Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

Between 0.160 inches and 0.205 inches

Terminal Length:

1.100 inches

Overall Diameter:

Between 0.080 inches and 0.107 inches

Function For Which Designed:

Transient suppressor

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

15.0 reverse breakdown voltage, dc

Current Rating Per Characteristic:

1.00 milliamperes collector current, dc peak

Power Rating Per Characteristic:

1500.0 watts small-signal input power, common-collector major

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Terminal Type And Quantity:

2 uninsulated wire lead

Specification Data:

80131-release 6741b professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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